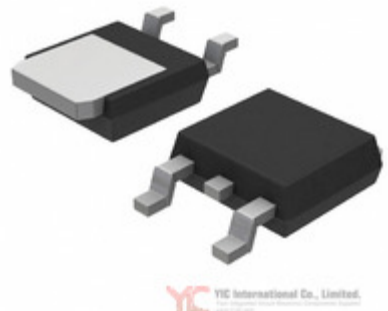

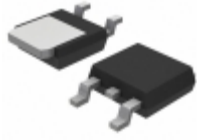


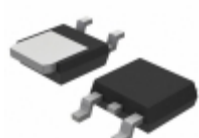
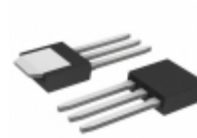
	<h2 style="color: red;">NTD18N06LT4G</h2>	
	Hersteller-Teilenummer:	NTD18N06LT4G
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET N-CH 60V 18A DPAK
	Datenblätter:	 NTD18N06LT4G.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 34633 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	NTD18N06LT4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 18A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	34633 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (Tj)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	2.1W (Ta), 55W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	18A (Ta)
Rds On (Max) @ Id, Vgs	65 mOhm @ 9A, 5V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	22nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	675pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	5V
Vgs (Max)	±15V
Verpackung	Tape & Reel (TR)

NTD18N06LT4G ist neu im Original, Suche NTD18N06LT4G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD18N06LT4G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD18N06LT4G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD18N06T4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 18A DPAK</p>	 <p>NTD18N06L-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 18A IPAK</p>	 <p>NTD20N03HL ON/ NTD20N03HL ON/</p>	 <p>NTD20N03 ON NTD20N03 ON</p>
 <p>NTD18N06LT4 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 18A DPAK</p>	 <p>NTD20N03G O NTD20N03G O</p>	 <p>NTD18N06L AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 18A DPAK</p>	 <p>NTD18N06L-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 18A IPAK</p>

heiße Teile

Mehr

- | | | | | |
|----------------|-----------------|-----------------|------------------|------------------|
| ⊗ NTD14N03R | ↔ NTD14N03R-001 | ⇒ NTD14N03R-1 | D NTD14N03R-1G | ⇒ NTD14N03RG |
| ⊣ NTD14N03RT4 | ⊗ NTD14N03RT4G | D NTD14N03RTCG | ⇒ NTD14N03T4G | ⇒ NTD15N06 |
| ⊗ NTD15N06L | ⊣ NTD15N06LG | ⊗ NTD15N06LT4 | ↔ NTD15N06LT4G | ⇒ NTD15N06T4 |
| D NTD15N06T4G | ⊗ NTD15N06VLT4 | ⊣ NTD15N07 | ⊗ NTD15N10 | ⇒ NTD18N06-001 |
| ⇒ NTD18N06-1G | ↔ NTD18N06G | ⊗ NTD18N06L | ⊣ NTD18N06L-1G | ⇒ NTD18N06LG |
| ↔ NTD18N06T4G | ⇒ NTD20N03 | D NTD20N03G | ⊗ NTD20N03HL | ⊣ NTD20N03L27 |
| ⊗ NTD20N03L27G | D NTD20N03L27T | ⇒ NTD20N03L27T4 | ↔ NTD20N03L27T4G | ⇒ NTD20N03RT4G |
| ⊣ NTD20N06 | ⊗ NTD20N06-001 | ↔ NTD20N06-1G | ⇒ NTD20N06HD | ⇒ NTD20N06HDLT4G |
| ⊗ NTD20N06HL | ⊣ NTD20N06L | ⊗ NTD20N06L-001 | D NTD20N06L-1G | ⇒ NTD20N06LG |
| ↔ NTD20N06LT4 | ⊗ NTD20N06LT4G | ⊣ NTD20N06T4G | ⊗ NTD20N06V | ⇒ NTD20P03 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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